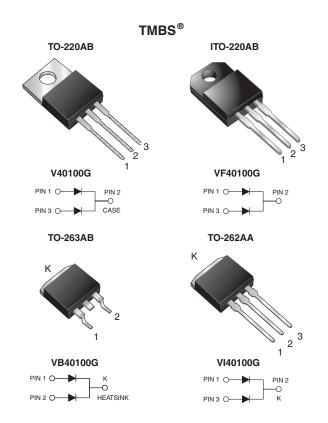


Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.42 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS					
IF _(AV)	2 x 20 A				
V_{RRM}	100 V				
I _{FSM}	200 A				
V _F at I _F = 20 A	0.67 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation

· Low thermal resistance



RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICALDATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

5-01D-002 and 0E0D 22-D102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V40100G	VF40100G	VB40100G	VI40100G	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	100					
Maximum average forward rectified currentper devic		40					
(fig. 1) per diode	F(AV)	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	200					
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 90 mH per diode	E _{AS}	230			mJ		
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}\text{C} \pm 2 ^{\circ}\text{C}$ per diode	I _{RRM}	1.0			А		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150				°C	

V40100G, VF40100G, VB40100G, VI40100G

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 min.	-			
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _A = 25 °C	- V _F	0.49	-	V		
	I _F = 10 A			0.59	-			
	I _F = 20 A			0.75	0.81			
	I _F = 5 A	T _A = 125 °C		0.42	-			
	I _F = 10 A			0.54	-			
	I _F = 20 A]		0.67	0.73			
Rverse current per diode (2)	V _R = 70 V	T _A = 25 °C	I _R	12	-	μΑ		
	v _R = 70 v	T _A = 125 °C		8	-	mA		
	V _R = 100 V	T _A = 25 °C		55	500	μA		
	v _R = 100 v	T _A = 125 °C		21	35	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V40100G	VF40100G	VB40100G	VI40100G	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	5.0	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40100G-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF40100G-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB40100G-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40100G-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40100G-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

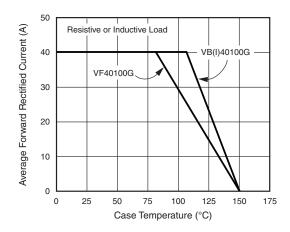


Fig. 1 - Maximum Forward Current Derating Curve

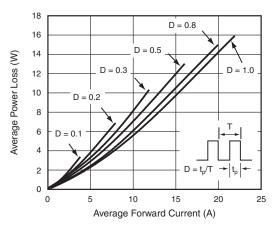


Fig. 2 - Forward Power Loss Characteristics





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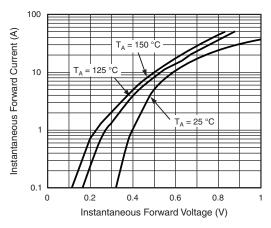


Fig. 3 - Typical Instantaneous Forward Characteristics

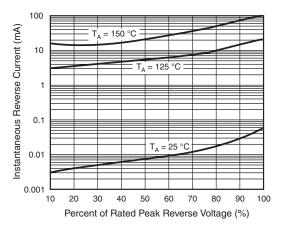


Fig. 4 - Typical Reverse Characteristics

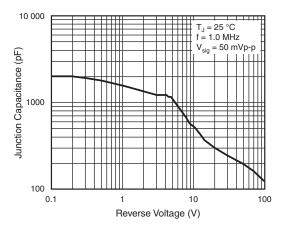


Fig. 5 - Typical Junction Capacitance

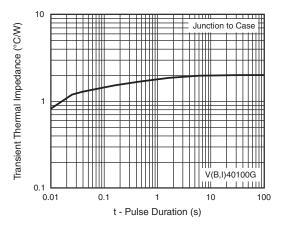


Fig. 6 - Typical Transient Thermal Impedance

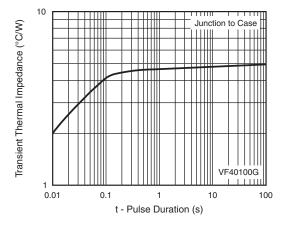


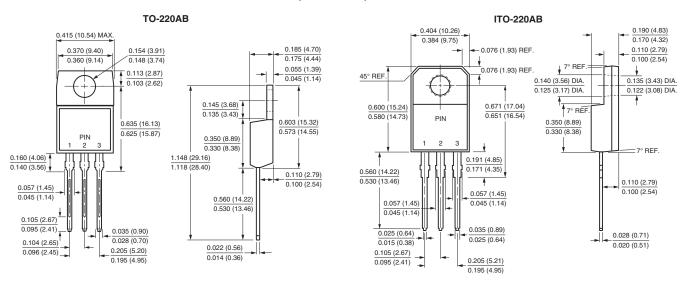
Fig. 7 - Typical Transient Thermal Impedance

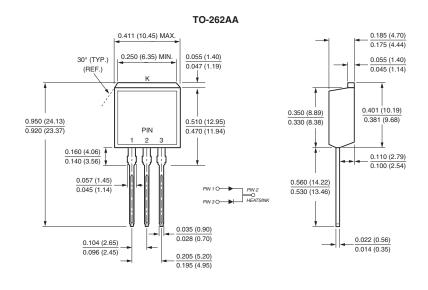


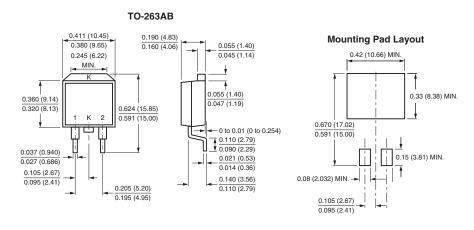


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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